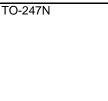


SCT4045DE N-channel SiC power MOSFET

Datasheet

V _{DSS}	750V
R _{DS(on)} (Typ.)	45mΩ
ا _D *1	34A
P _D	115W

Outline



• Features

- 1) Low on-resistance
- 2) Fast switching speed
- 3) Fast reverse recovery
- 4) Easy to parallel
- 5) Simple to drive
- 6) Pb-free lead plating ; RoHS compliant

Application

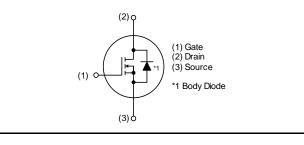
- Solar inverters
- DC/DC converters
- Switch mode power supplies
- Induction heating
- Motor drives

• Absolute maximum ratings $(T = 25^{\circ}C)$

•Absolute maximum ratings ($T_c = 25^\circ$	0)		ī	-
Parameter		Symbol	Value	Unit
Drain - source voltage		V _{DSS}	750	V
Continuous drain and source current		ı ı *1	34	Α
$T_c = 100^{\circ}C$	$V_{GS} = V_{GS_on}$	Ι _D , Ι _S ^{*1}	24	Α
Pulsed drain current	$V_{GS} = V_{GS_{on}}$	I _{D,pulse} *2	61	А
Body diode pulsed forward current	$V_{GS} = 0 V$	^{*3} S,pulse	34	А
Body diode surge forward current	$V_{GS} = 0 V$	I _{S,pulse} *4	61	А
Gate - source voltage (DC)		V _{GSS}	-4 to +21	V
Gate - source surge voltage (t _{surge} < 300ns)		V _{GSS_surge} *5	-4 to +23	V
Recommended turn-on gate - source dri	ive voltage	V _{GS_on} *6	+15 to +18	V
Recommended turn-off gate - source drive voltage		$V_{GS_{off}}$	0	V
Virtual junction temperature		T _{vj}	175	°C
Range of storage temperature		T _{stg}	-40 to +175	°C



Inner circuit



Packaging specifications

	Packing	Tube
	Reel size (mm)	-
Tuno	Tape width (mm)	-
Туре	Basic ordering unit (pcs)	30
	Taping code	C11
	Marking	SCT4045DE

•Electrical characteristics ($T_{vj} = 25^{\circ}C$ unless otherwise specified)

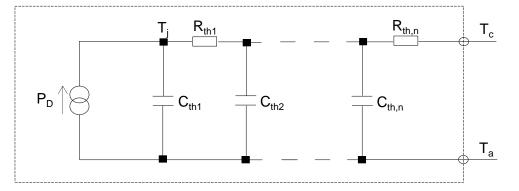
Doromotor	Symbol	Conditions		L Incit			
Parameter	Symbol Conditions		Min.	Тур.	Max.	Unit	
Drain - Source breakdown voltage	V _{(BR)DSS}	$V_{GS} = 0 V, I_D = 5.3 mA$ $T_{vi} = 25^{\circ}C$	750	-	-	V	
Zero Gate voltage Drain current	I _{DSS}	$V_{GS} = 0 V, V_{DS} = 750V$ $T_{vj} = 25^{\circ}C$	-	1	80	μA	
		T _{vj} = 150°C	-	10	-		
Gate - Source leakage current	I _{GSS+}	V_{GS} = +21V , V_{DS} = 0V	-	-	100	nA	
Gate - Source leakage current		$V_{GS} = -4V$, $V_{DS} = 0V$	-	-	-100	nA	
Gate threshold voltage	$V_{GS (th)}^{*7}$	$V_{DS} = 10V, I_{D} = 8.89mA$	2.8	-	4.8	V	
Static Drain - Source on - state resistance	R _{DS(on)} *8	$V_{GS} = 18V, I_D = 17A$ $T_{vj} = 25^{\circ}C$ $T_{vj} = 150^{\circ}C$	-	45 77	59 -	mΩ	
Gate input resistance	R_G	f = 1MHz, open drain	-	4	-	Ω	

•Thermal resistance

Parameter	Symbol	Values			Unit
Faranielei	Symbol	Min.	Тур.	Max.	Offic
Thermal resistance, junction - case	R_{thJC}^{*9}	-	0.98	1.3	K/W

•Typical Transient Thermal Characteristics

Symbol	Value	Unit	Symbol	Value	Unit
R _{th1}	1.7 ×10 ⁻¹		C _{th1}	3.6 ×10 ⁻⁴	
R _{th2}	4.1 ×10 ⁻¹	K/W	C _{th2}	1.5 ×10 ⁻³	Ws/K
R _{th3}	4.0 ×10 ⁻¹		C _{th3}	6.5 ×10 ⁻³	





•Electrical characteristics ($T_{vj} = 25$ °C unless otherwise specified)

Doromotor	Sumbol	Conditions		Unit			
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Transconductance	g _{fs} *8	$V_{DS} = 10V, I_{D} = 17A$	-	9.4	-	S	
Input capacitance	C _{iss}	$V_{GS} = 0V$	-	1460	-		
Output capacitance	C _{oss}	V _{DS} = 500V	-	69	-	pF	
Reverse transfer capacitance	C _{rss}	f = 1MHz	-	5	-		
Effective output capacitance, energy related	C _{o(er)}	$V_{GS} = 0V$ $V_{DS} = 0V$ to 500V	-	90	-	pF	
Total Gate charge	Q _g *8	V _{DS} = 500V I _D = 17A	-	63	-		
Gate - Source charge	Q _{gs} *8	$V_{GS} = 18V$	-	14	-	nC	
Gate - Drain charge	Q _{gd} *8	See Fig. 1-1, 1-2.	-	19	-		
Turn - on delay time	t _{d(on)} *8	$V_{DS} = 500V$ $I_{D} = 17A$	-	5.8	-		
Rise time	t _r *8	V _{GS} = +18V / 0V	-	28	-	20	
Turn - off delay time	t _{d(off)} *8	$R_G = 3.3\Omega$, L = 250µH E _{on} includes diode	-	29	-	ns	
Fall time	t _f *8	reverse recovery $L_{\sigma} = 50 \text{nH}, C_{\sigma} = 10 \text{pF}$	-	12	-		
Turn - on switching loss	Eon *8	See Fig. 2-1, 2-2, 2-3.	-	210	-	1	
Turn - off switching loss	E _{off} *8		-	33	-	μJ	



●Body diode electrical characteristics (Source-Drain) (T_{vj} = 25°C unless otherwise specified)

Parameter	Symbol	Conditions	Values			Unit	
Farameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Forward voltage	V_{SD}^{*8}	$V_{GS} = 0V, I_D = 17A$	-	3.3	-	V	
Reverse recovery time	t _{rr} *8	I _F = 17A V _R = 500V	-	19	-	ns	
Reverse recovery charge	Q _{rr} *8	di/dt = 1700A/µs	-	86	-	nC	
Peak reverse recovery current	I _{rrm} *8	$L_{\sigma} = 50$ nH, $C_{\sigma} = 10$ pF See Fig. 3-1, 3-2.	-	9	-	А	

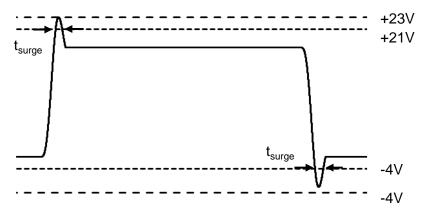
*1 Limited by maximum T_{vj} and for Max. R_{thJC} .

*2 $P_W \le 10\mu s$, Duty cycle $\le 1\%$

*3 Only for body-diode, Repititive pulse, PW \leq 500ns, Duty cycle \leq 5%

*4 When used as a protective function, PW \leq 10µs

*5 Example of acceptable V_{GS} waveform



- *6 Please be advised not to use SiC-MOSFETs with V_{GS} below 10V as doing so may cause thermal runaway.
- *7 Tested after applying V_{GS} = 21V for 100ms.

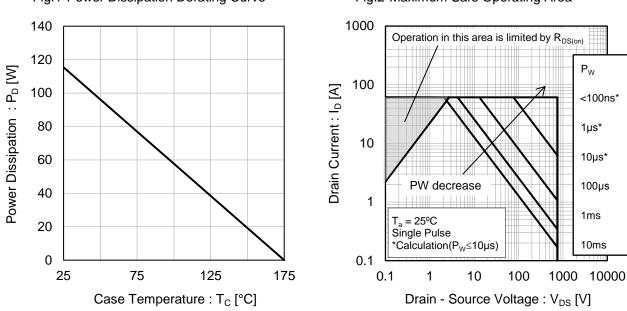
*8 Pulsed

*9 Measured conformable to JESD51-14.

See the application note "rthjc_measurement_and_usage_an-e.pdf". Link

URL: https://fscdn.rohm.com/en/products/databook/applinote/discrete/common/rthjc_measurement_and_usage_an-e.pdf





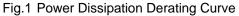
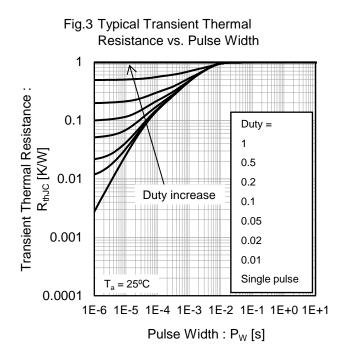


Fig.2 Maximum Safe Operating Area





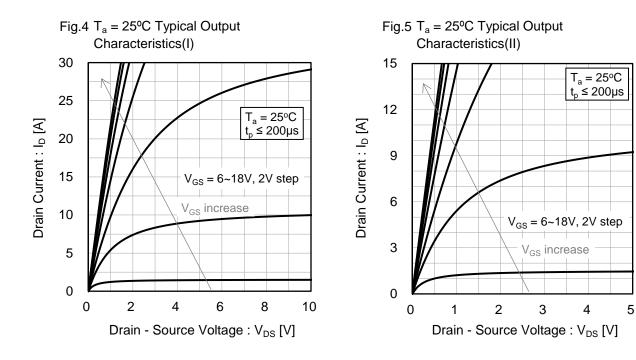
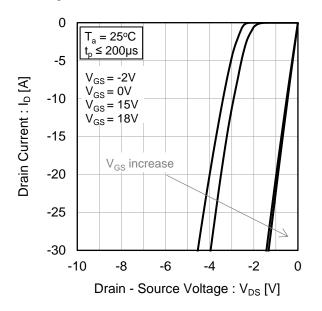
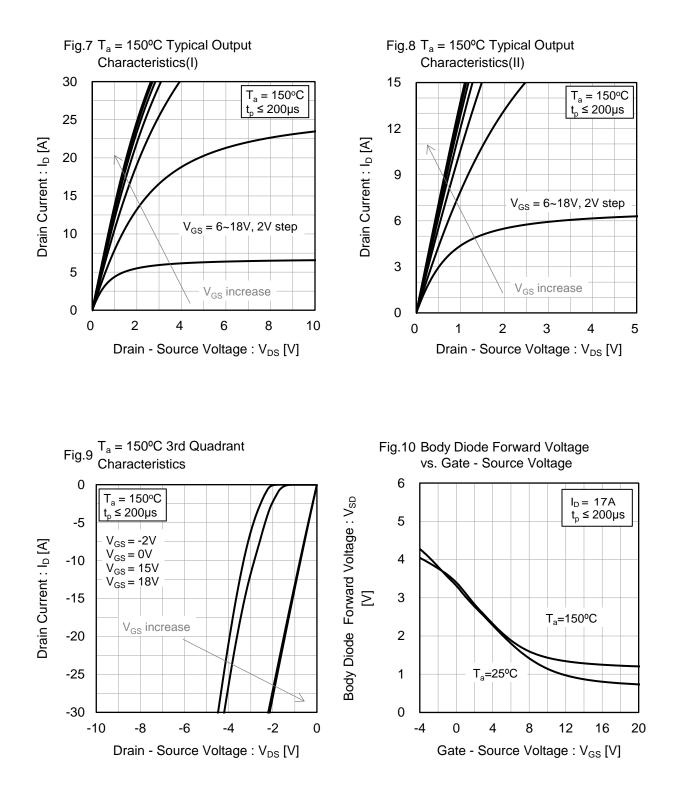


Fig.6 $T_a = 25^{\circ}C$ 3rd Quadrant Characteristics









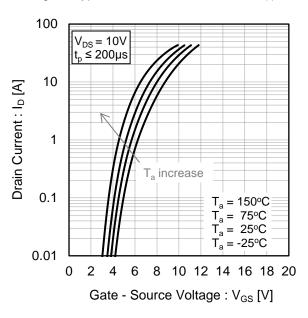
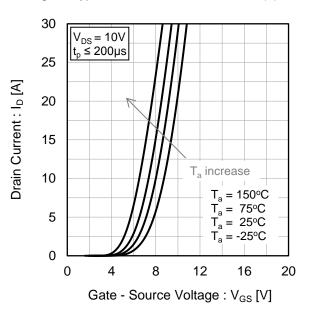


Fig.11 Typical Transfer Characteristics (I)

Fig.12 Typical Transfer Characteristics (II)



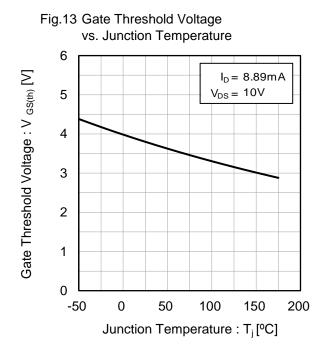
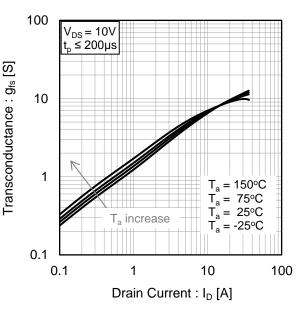
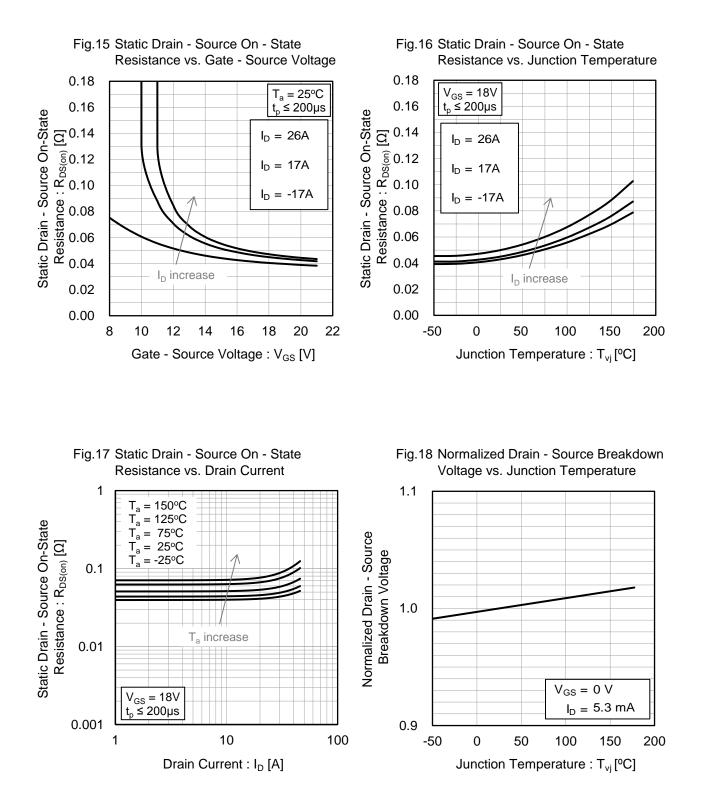


Fig.14 Transconductance vs. Drain Current









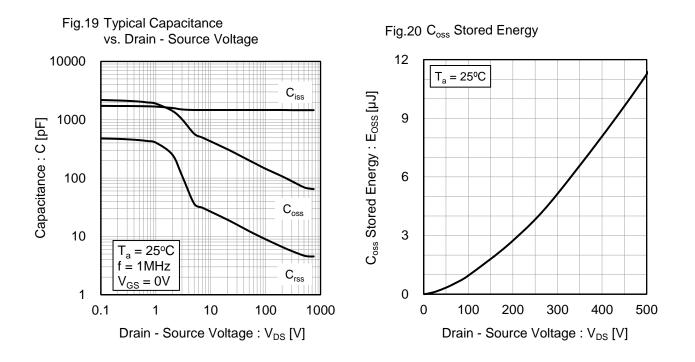
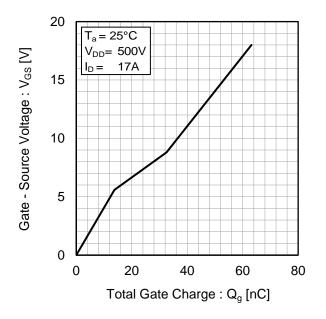
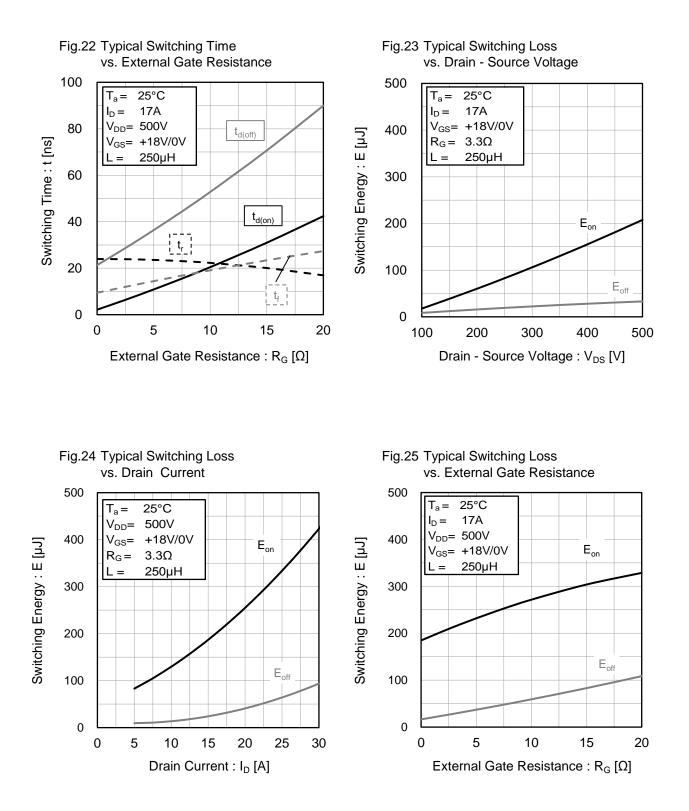


Fig.21 Dynamic Input Characteristics









Measurement circuits and waveforms

Fig.1-1 Gate Charge Measurement Circuit

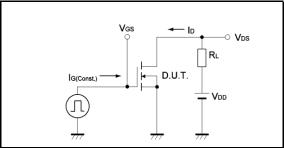


Fig.2-1 Switching Characteristics Measurement Circuit

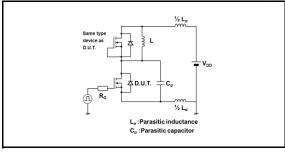


Fig.2-3 Waveforms for Switching Energy Loss

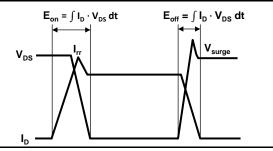


Fig.3-1 Reverse Recovery Time Measurement Circuit

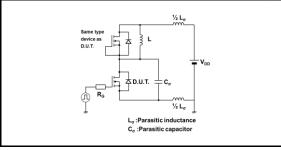


Fig.1-2 Gate Charge Waveform

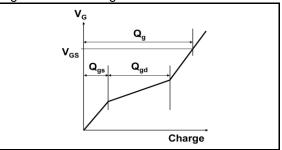


Fig.2-2 Waveforms for Switching Time

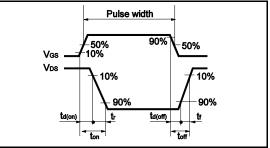
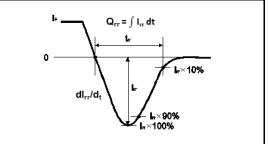


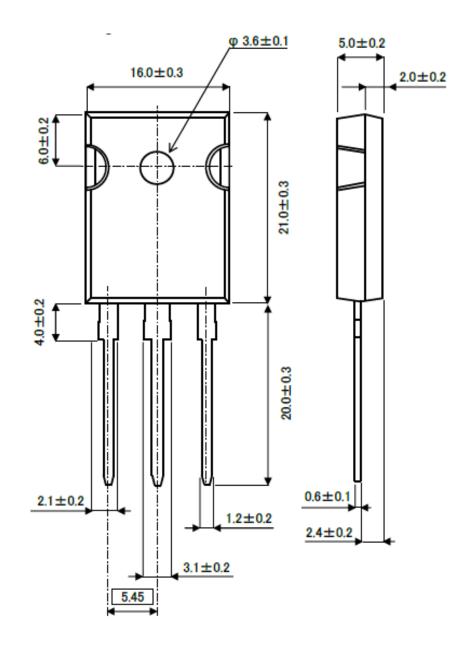
Fig.3-2 Reverse Recovery Waveform

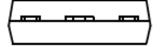






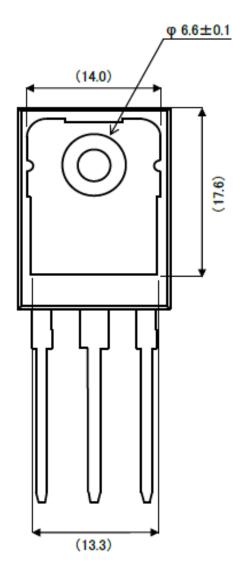
Package Dimensions





Unit: mm



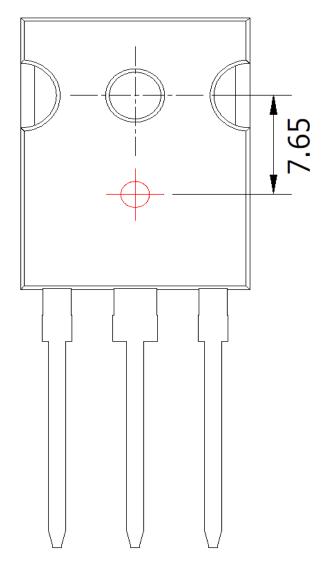


Unit: mm





•Die Bonding Layout



•Front view of the packaging.

·Dimensions are design values.

·If the heat sink is to be installed, it should be in contact with the die bonding point.

Unit: mm



	Notes
1)	The information contained herein is subject to change without notice.
2)	Before you use our Products, please contact our sales representative and verify the latest specifica- tions.
3)	Although ROHM is continuously working to improve product reliability and quality, semicon ductors can break down and malfunction due to various factors. Therefore, in order to prevent personal injury or fire arising from failure, please take safety measures such as complying with the derating characteristics, implementing redundant and fire prevention designs, and utilizing backups and fail-safe procedures. ROHM shall have no responsibility for any damages arising out of the use of our Poducts beyond the rating specified by ROHM.
4)	Examples of application circuits, circuit constants and any other information contained herein are provided only to illustrate the standard usage and operations of the Products. The periphera conditions must be taken into account when designing circuits for mass production.
5)	The technical information specified herein is intended only to show the typical functions of and examples of application circuits for the Products. ROHM does not grant you, explicitly or implicitly any license to use or exercise intellectual property or other rights held by ROHM or any othe parties. ROHM shall have no responsibility whatsoever for any dispute arising out of the use or such technical information.
6)	The Products specified in this document are not designed to be radiation tolerant.
7)	For use of our Products in applications requiring a high degree of reliability (as exemplified below), please contact and consult with a ROHM representative : transportation equipment (i.e cars, ships, trains), primary communication equipment, traffic lights, fire/crime prevention, safety equipment, medical systems, and power transmission systems.
8)	Do not use our Products in applications requiring extremely high reliability, such as aerospace equipment, nuclear power control systems, and submarine repeaters.
9)	ROHM shall have no responsibility for any damages or injury arising from non-compliance with the recommended usage conditions and specifications contained herein.
10)	ROHM has used reasonable care to ensure the accuracy of the information contained in this document. However, ROHM does not warrants that such information is error-free, and ROHM shall have no responsibility for any damages arising from any inaccuracy or misprint of such information.
11)	Please use the Products in accordance with any applicable environmental laws and regulations such as the RoHS Directive. For more details, including RoHS compatibility, please contact a ROHM sales office. ROHM shall have no responsibility for any damages or losses resulting non-compliance with any applicable laws or regulations.
12)	When providing our Products and technologies contained in this document to other countries you must abide by the procedures and provisions stipulated in all applicable export laws and regulations, including without limitation the US Export Administration Regulations and the Foreign Exchange and Foreign Trade Act.
13)	This document, in part or in whole, may not be reprinted or reproduced without prior consent of



Thank you for your accessing to ROHM product informations. More detail product informations and catalogs are available, please contact us.

ROHM Customer Support System

http://www.rohm.com/contact/

General Precaution

- 1. Before you use our Products, you are requested to care fully read this document and fully understand its contents. ROHM shall not be in an y way responsible or liable for failure, malfunction or accident arising from the use of a ny ROHM's Products against warning, caution or note contained in this document.
- 2. All information contained in this docume nt is current as of the issuing date and subject to change without any prior notice. Before purchasing or using ROHM's Products, please confirm the latest information with a ROHM sale s representative.
- 3. The information contained in this document is provided on an "as is" basis and ROHM does not warrant that all information contained in this document is accurate an d/or error-free. ROHM shall not be in an y way responsible or liable for any damages, expenses or losses incurred by you or third parties resulting from inaccuracy or errors of or concerning such information.